

View Online at <https://aerobasegroup.com/nsn/5961-00-401-6787>

Inclosure Material:

Metal

Overall Length:

0.260 inches

Terminal Length:

0.150 inches

Overall Height:

0.040 inches

Overall Width:

0.150 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open all transistor and 45.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

600.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Test Data Document:

94756-472-0888 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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